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10/21/01  
A. Well

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant : Shunpei Yamazaki, et al. Art Unit : 2823  
Serial No.: 08/994,038 Examiner : W. David Coleman  
Filed : December 18, 1997  
Title : CHARGE TRANSFER SEMICONDUCTOR DEVICE AND MANUFACTURING METHOD THEREOF

Box AF  
Commissioner for Patents  
Washington, D.C. 20231

AMENDMENT

In response to the Official Action dated July 3, 2001,  
Paper No. 22, in the above-referenced application, please amend  
the above-identified application as follows.

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OCT 18 2001  
TLC 2800 MAIL ROOM

In the Claims:

Please amend the claims as follows:

1. (Amended) A charge transfer semiconductor device  
comprising:  
a crystalline semiconductor film having a plurality of  
crystals extending in a crystal growth direction;

CERTIFICATE OF MAILING BY FIRST CLASS MAIL

I hereby certify under 37 CFR §1.8(a) that this correspondence is being deposited with the United States Postal Service as first class mail with sufficient postage on the date indicated below and is addressed to the Commissioner for Patents, Washington, D.C. 20231.

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*Susan M. Regan*

Susan Regan

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